## NSN 5961-01-055-5273

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Inclosure Material:
Metal
Overall Length:
0.520 inches
Overall Height:
0.710 inches
Overall Diameter:
1.250 inches
End Application:
An/mrc-108
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-36
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
60.0 breakdown voltage, collector-to-emitter, base open and 80.0 collector to base voltage/static/emitter open
Current Rating Per Characteristic:
50.00 amperes source cutoff current
Power Rating Per Characteristic:
70.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
25.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 pin and 1 threaded stud
Shelf Life:

N/a

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Demilitarization:

No

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